

SRM Institute of Science and Technology College of Engineering and Technology

Batch 1 SET A

DEPARTMENT OF ECE

SRM Nagar, Kattankulathur – 603203, Chengalpattu District, Tamilnadu

Academic Year: 2024-2025 (EVEN)

Test: FT III Date: 07.04.2025

Course Code & Title: 21ECC304TR Microwave and Optical Communication Duration: 08:00 am – 09:40 am

Year & Sem.: III & VI Max. Marks: 50

Answer Key

Course Articulation Matrix:

	21ECC304TR - Microwave & Optical Communication	Program Outcomes (POs)														
		Graduate Attributes PSO														
COs	Course Outcomes (COs)	1	2	3	4	5	6	7	8	9	10	11	12	1	2	3
1	Familiarize the concept of microwave transmission and generation	3	2	-	-	-	-	-	-	-	-	-	-	3	-	-
2	Realize systematic methods to design, analyze S-parameters of microwave devices	3	2	-	-	-	-	-	-	-	ı	-	-	3	-	-
3	Identify different measurement techniques for determining various parameters and to gain knowledge on microwave measurements and the techniques with associated equipment	2	-	-	3	-	-	-	-	-	-	-	-	3	-	-
4	Discover complete information on the fundamentals of light transmission through fiber and their characterization and mechanism	3	2	-	-	-	-	-	-	-	-	-	-	3	-	-
5	Recognize the link power budget design considerations of optical communication system	3	-	2	-	-	-	-	-	-	1	-	-	-	2	

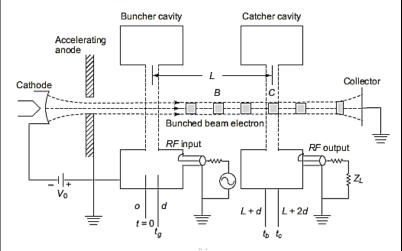
	Part – A $(1x20 = 20 \text{ Marks})$ Answer all the questions							
Q. No.	Question	Marks	BL	CO	PO			
	 i) TRAPATT diodes differ from IMPATT diodes in that they: a) Operate at higher efficiency and lower breakdown voltage b) Operate at lower efficiency and higher breakdown voltage c) Have a lower carrier concentration d) Use quantum well structures for operation 	1	2	1	1			
1 (a)	 ii) The main principle behind the operation of a tunnel diode is: a) Avalanche Breakdown b) Negative Differential Resistance due to Quantum Tunneling c) Thermal Ionization d) Charge Storage Effect 	1	2	1	1			
	iii) Which material is commonly used in microwave isolators for non-reciprocal behavior?a) Ferriteb) Siliconc) GaAsd) Copper	1	1	2	1			
	 iv) Which type of attenuator provides constant attenuation over a wide frequency range? a) Waveguide variable attenuator b) Resistive pad attenuator c) PIN diode attenuator d) Ferrite-based attenuator 	1	1	2	1			

- i) A space agency is developing a deep-space communication system that requires a high-power RF amplifier to enhance weak signals received from a distant probe. The chosen technology relies on velocity modulation to amplify microwave signals efficiently.
- (a) Explain the working principle behind the amplification process and its significance in space communication. (6 Marks)

Two-cavity Klystron Amplifier

1 (b)

A high velocity electron beam produced by the accelerating anode is successively passed through an input reentrant cavity resonator (buncher cavity) grid, a field free drift space of length L, an output re-entrant cavity resonator (catcher cavity) grid and finally collected by a collector electrode. The electron beam is focused to travel axially without spreading during transit by applying an axial magnetic field produced by an external coil current. The input RF signal to be amplified excites the buncher cavity with a coupling loop. The combination of the anode voltage V0 and the cavity gap width d are such that the transit of electrons through each cavity gap is less than the quarter of the time period T of the input signal cycle. (2 marks)



(1 Mark)

The electrons passing through the buncher grids accelerated/retarded/passed through with unchanged initial dc velocity depending upon when they encounter the RF signal field at the buncher cavity gap at positive/negative/zero crossing phase of the cycle, respectively. Thus, the electron beam is velocity modulated to form bunches or undergoes density modulation in accordance with the input RF signal cycle. While passing through the catcher cavity grid, this density modulated electron beam induces RF current in the output cavity and thereby excites the RF field in the output cavity at input signal cycle. The phase of field in the output cavity is opposite to that of the input cavity so that the bunched electrons are retarded by the output gap voltage. The loss of kinetic energy of the electrons on retardation process transfers RF energy to the output cavity continuously at signal cycle. The amplitude of the signal at output cavity attains a steady large value when the loss of kinetic energy of the bunched electrons compensates the output cavity circuit losses. The amplified signal is coupled out from the catcher cavity through a current loop to the load. (3 marks)

1

2

3

8

(b) The system operates at 9 GHz with an input power of 50 mW and a power gain of 30 dB. Determine the output power. (2 Marks)				
$P_{ m out} = P_{ m in} imes 10^{G_{ m dB}/10}$ (1 mark) $P_{ m out} = 50 ext{ Watts}$ (1 mark)				
ii) (a) If an input power of 40 W is applied, and it splits into two outputs maintaining equal phase but different magnitudes (3:1 ratio), determine the power at each output port. (2 Marks) power Splitter:				
power divider				
$R = \frac{P1}{P2}$ $Pin = P1+P2$				
$PI = \frac{R}{R+1} \times Pin$				
given Pa = 1. Pin R+1 CI marke) pin = 40 W				
Power ratio R=3:1	8	3	2	2
PI = 30W & P2 = 10W] (1 mare)				
(b) A waveguide junction exhibits different power-splitting behavior depending on the orientation of the incident wave. Derive the S parameter of the mentioned device. (6 Marks) Magic Tee (Hybrid Tee) A hybrid TEE is formed with the combination of the E-plane and H-plane tees and is called a magic-T.				
Difference or E-arm Collinear arm2 E-plane T Collinear arm1 Collinear arm1 H-plane T H-arm (a) Difference or E-arm Collinear arm2 E-plane T H-plane T H-plane T H-arm (b)				
Fig. 6.49 Magic-T s with ports 3 and 4 interchanged (1 mark)				

The magic-T has the following characteristics when all the ports are terminated with a matched loads.

- If two waves of equal magnitude and equal phase are fed into ports 1 and 2, the output at Port 3 is subtractive and becomes zero and total output will appear additively at the port 4. Hence, Port 3 is called the difference or E-arm and 4, the sum or H-arm.
- A wave incident at Port 3 (E-arm) divides equally between ports 1 and 2 but is opposite in phase with no coupling to Port 4 (H-arm). Thus, S13 = -S23, S43= 0
- A wave incident at Port 4 (H-arm) divides equally between ports 1 and 2 in phase with no coupling to port 3 (E-arm). Thus,
- S14 = S41 = 1/2 = S24 = S42 and S34 = 0
- A wave fed into one collinear port, 1 or 2, will not appear in the other collinear Ports, 2 or 1, respectively. Hence, two collinear ports 1 and 2 are isolated from each other, making S12 = S21 = 0

A magic-T can be matched by putting tuning screws suitably in the E and H-arms without destroying the symmetry of the junctions. Therefore, for an ideal lossless magic-T matched at ports 3 and 4, S33 = S44 = 0.

The procedure of derivation of the S-matrix considers the symmetry property at the junction for which S14 = S41 = S24 = S42, S31 = S13 = -S23 = -S32, S34 = S43 = 0, S12 = S21 = 0.

(2 marks)

Therefore, the S-matrix for a magic-T, matched at ports 3 and 4 given by

$$[S] = \begin{bmatrix} S_{11} & S_{12} & S_{13} & S_{14} \\ S_{12} & S_{22} & -S_{13} & S_{14} \\ S_{13} & -S_{13} & 0 & 0 \\ S_{14} & S_{14} & 0 & 0 \end{bmatrix}$$

From the unitary property applied to rows 1 and 2, we get

$$|S_{11}|^2 + |S_{12}|^2 + |S_{13}|^2 + |S_{14}|^2 = 1$$

$$|S_{12}|^2 + |S_{22}|^2 + |S_{13}|^2 + |S_{14}|^2 = 1$$

Subtracting these two equations:

$$|S_{11}|^2 - |S_{22}|^2 = 0$$
 or, $|S_{11}| = |S_{22}|$

Form the unitary property applied to rows 3 and 4,

$$\begin{split} &2\;|S_{13}|^2=1,\quad\text{or}\quad|S_{13}|=1/\sqrt{2}\\ &2\;|S_{14}|^2=1,\quad\text{or}\quad|S_{14}|=1/\sqrt{2} \end{split}$$

Substituting these values in Eq. (6.103),

$$|S_{11}|^2 + |S_{12}|^2 + 1/2 + 1/2 = 1$$
 or, $|S_{11}|^2 + |S_{12}|^2 = 0$

which is valid if

$$S_{11} = S_{12} = 0$$

From Eqs (6.105) and (6.109), $S_{22} = 0$

Therefore,
$$[S] = \begin{bmatrix} 0 & 0 & S_{13} & S_{13} \\ 0 & 0 & -S_{13} & S_{13} \\ S_{13} & -S_{13} & 0 & 0 \\ S_{13} & S_{13} & 0 & 0 \end{bmatrix}$$

where

$$|S_{13}| = 1/\sqrt{2} = |S_{14}|$$

(2 marks)

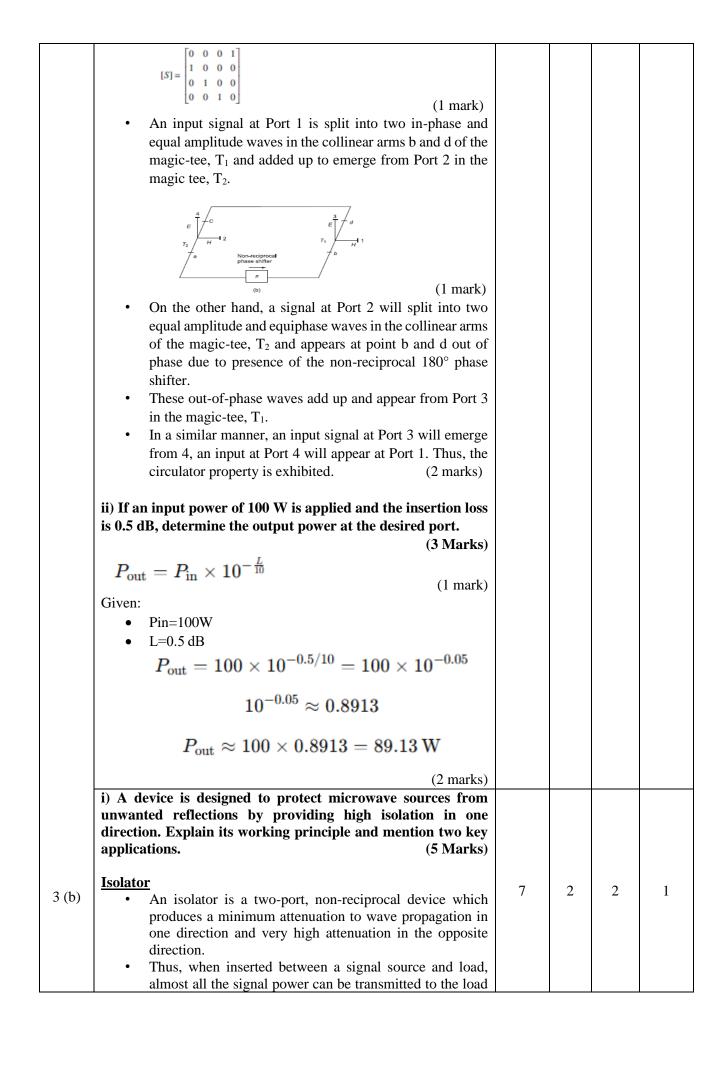
By proper choice of reference planes in arms 3 and 4, it is possible to make both S13 and S14 real, resulting in the final form of S-matrix of magic-T.

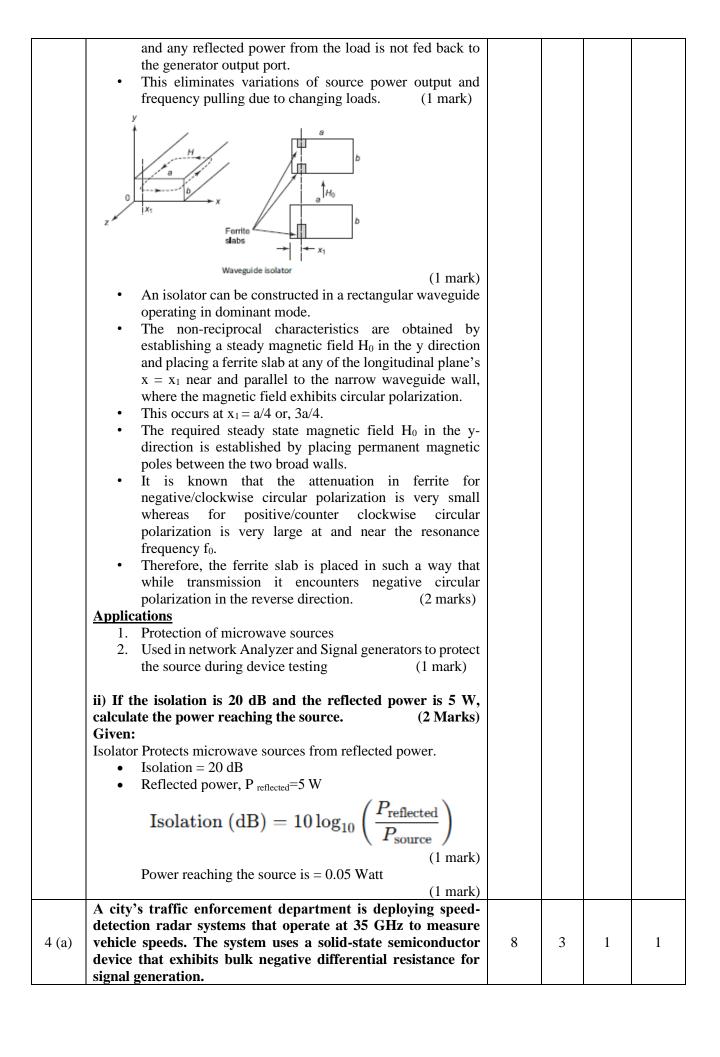
	$\begin{bmatrix} 0 & 0 & 1 & 1 \end{bmatrix}$				
	$[S] = 1/\sqrt{2} \begin{vmatrix} 0 & 0 & 1 & 1 \\ 0 & 0 & -1 & 1 \\ 1 & -1 & 0 & 0 \\ 1 & 1 & 0 & 0 \end{vmatrix}$				
	$\begin{bmatrix} 1 & -1 & \sqrt{2} \\ 1 & -1 & 0 & 0 \end{bmatrix}$				
	[1 1 0 0]				
	For the structure (b) where ports 3 and 4 are interchanged, the S-matrix becomes				
	[0 0 1 1]				
	$[S] = 1/\sqrt{2} \begin{bmatrix} 0 & 0 & 1 & 1 \\ 0 & 0 & 1 & -1 \\ 1 & 1 & 0 & 0 \\ 1 & -1 & 0 & 0 \end{bmatrix}$				
	$[S] = 1/\sqrt{2} \begin{bmatrix} 1 & 1 & 0 & 0 \end{bmatrix}$				
	1 -1 0 0				
	(1 mark)				
	Part – B (2 x 15 = 30 Marks)	. 4: aa			
2 (-)	Instructions: Answer any two out of three ques	suons	l		
2 (a)	An aerospace company is designing an airborne radar system				
	where a compact, stable frequency source is required for				
	signal transmission. Due to space constraints, a single-				
	resonator device is selected for generating microwave signals.				
	i) Explain the working mechanism of this frequency generator				
	and its significance in radar applications. (6 Marks)				
	Reflex Klystron Oscillator				
	The electron beam emitted from the cathode K is accelerated by				
	the grid G and passes through the cavity anode AB to the repeller				
	space between the cavity anode and the repeller electrode R. The				
	feedback required to maintain oscillations within the cavity is				
	obtained by reversing the electron beam emitted from K towards				
	R and sending it back through the cavity. The electrons in the beam				
	are velocity modulated before the beam passes through the cavity				
	1				
	second time and will give up the energy to the cavity to maintain				
	oscillations. This type of a klystron oscillator is called a reflex				
	klystron because of the reflex action of the electron beam.				
	(2 marks)				
	• -V _R				
	Repeller plate	_	_		_
	R Electron flow	8	3	1	2
	Repeller Grids				
	space Grid gap				
	Re-entrant Output				
	resonant magnetic coupling				
	loop through				
	Coaxial line				
	+ Accelerating				
	Vo + Grid				
	Cathode				
	+ - -				
	Resonator 7/1/1 Ground				
	potential				
	(1 mark)				
	Mechanism of Oscillation				
	Due to dc voltage in the cavity circuit, RF noise is generated in the				
	cavity. This electromagnetic noise field in the cavity becomes				
	pronounced at cavity resonant frequency. The electrons passing				
	through the cavity gap d experience this RF field and are velocity				
	modulated in the following manner. The electrons which				
	encountered the positive half cycle of the RF field in the cavity gap				
<u> </u>	chooding of the positive half cycle of the KI Held III the cavity gap		l .		

d will be accelerated, those (reference electrons) b which encountered zero RF field will pass with unchanged original velocity, and the electrons c which encountered the negative half cycle will be retarded on entering the repeller space. The RF power is coupled to the output load by means of a small loop which forms the centre conductor of the coaxial line. When the power delivered to the cavity by the electrons becomes equal to the total power loss in the cavity system, a steady microwave oscillation is generated and maintained at resonant frequency of the cavity. (2 marks) Significance: • Klystrons play a crucial role in radar applications due to their ability to generate high-power microwave signals with excellent frequency stability and efficiency. • They provide high gain with minimal noise, making them ideal for detecting weak signals over long distances. (1 mark) ii) Given a repeller voltage of -300V and a transit time factor based on an electron path length of 1 mm, estimate the electron transit time. (2 Marks)				
given				
Repeller Voltage Vr = -300V				
100-86				
Repeller Voltage $V_r = -300V$ length $l = 1 \text{ mm}$ $= 1 \times 10^3 \text{ m}$				
transit fine $t=7$				
t = 2L				
V2e[Vr]				
W.k.t $e=1.6 \times \overline{10}^{9} \text{ c}$, $m=9.1 \times \overline{10}^{8} \text{ kg}$ Substitute the values, $t=\frac{2 \times 1 \times \overline{10}^{3}}{\sqrt{2 \times 1.6 \times \overline{10}^{9} \times 300}}$ $q.1 \times \overline{10}^{3}$				
Substitute the values,				
$t = \frac{2 \times 1 \times 10^3}{10^3}$				
2x1.6x1019 x 300				
t = 194.72 ps				
Formula: 1 mark, Answer: 1 mark				
An RF system consists of multiple resonant chambers that determine its operational frequency. If the dimensions of these				
chambers are altered, how does it affect the output? (7 Marks) Magnetron Oscillator	_			2
Magnetrons are crossed field tubes (M-type) in which the dc magnetic fi eld and the dc electric field are perpendicular to each other. Magnetron consists of a cylindrical cathode K of finite-	7	3	1	2
length-radius a at the centre surrounded by a cylindrical anode A				

2 (b)

	of radius b. The anode is a slow-wave structure consisting of				
	several re-entrant cavities equispaced around the circumference				
	and coupled together through the anode–cathode space by means				
	of slots. Radial electric field is established by dc voltage V0 in				
	between the cathode and the anode and an axial dc magnetic flux				
	denoted by B0 is maintained in the positive z-direction by means				
	of a permanent magnet or an electromagnet. (2 marks)				
	B ₀ Anode V ≈ V ₀				
	V ₀ = 7				
	A Cathode $V=0$				
	Slot Cathode				
	(o () () () ()				
	Anode Z Co-axial line				
	() () () ()				
	Bo Output coupling loop				
	Basic magnetron oscillator Electron trajectory				
	(1 mark)				
	Magnetron theory of operation is based on the motion of				
	electrons under the influence of combined electric and				
	magnetic fi elds. The electrons emitted from the cathode				
	try to travel to the anode. But with the influence of crossed				
	fi elds E and H in the space between the anode and the				
	cathode, it experiences resultant force $F = -eE - e(v \times B)$,				
	where v is the velocity vector of the electron considered				
	and takes a curved trajectory.				
	• Due to excitation of the anode cavities by RF noise voltage				
	in the biasing circuit, the RF field lines are fringed out of				
	the cavity slot to the space between the anode and cathode.				
	(2 marks)				
	• In a magnetron, altering the dimensions of the resonant				
	cavities changes their resonant frequency, thereby shifting				
	the magnetron's output frequency. (1 mark)				
	i) A three-port non-reciprocal device is used in radar systems				
3 (a)	to ensure signal flow in a specific direction. Explain its				
	operation and how it achieves isolation between ports.				
	(5 Marks)				
	Circulators:				
	• A circulator is a multiport junction in which the wave can				
	travel from one port to the next immediate port in one				
	direction only.				
	 Commonly used circulators are three-port or four-port 	8	3	2	1
	passive devices although a greater number of ports is				
	possible.				
	• A four-port circulator can be constructed from two magic-				
	T's and a nonreciprocal 180° phase shifter or a				
	combination of two 3 dB side hole directional couplers				
	with two non-reciprocal phase shifters.				
	A perfectly matched, lossless, and non-reciprocal four-				
1	11 pericetly materied. Tobblebb. and from rectificed from				
	port circulator has S-matrix: (1 Mark)				





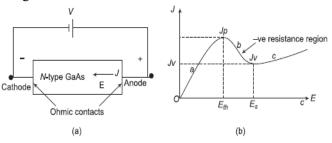
i) Describe the principle enabling the generation of microwave signals in this system. (6 Marks)

Gunn Diode

 There are two principle modes of operation that result in microwave oscillations in a Gunn diode. These are the Gunn mode or the transit-time (TT) mode and the limitedspace-charge (LSA) mode.

I-V Characteristics and Basic Operation

 When the GaAs sample is biased with a dc source of voltage V, an electric fi eld is generated inside the sample with electric current I. The typical characteristic of current density J vs. electric fi eld E in the semiconductor is shown in Fig. below.



Gunn diode biasing and I-V characteristics

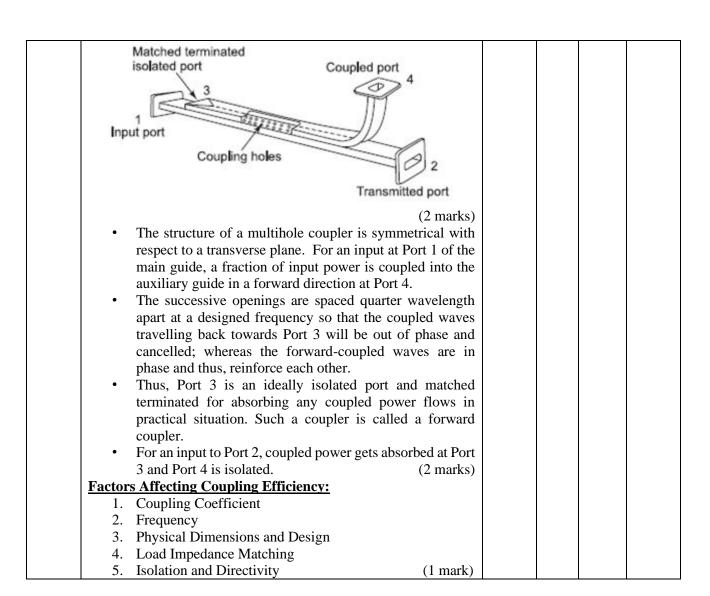
(2 marks)

- It is seen that when the electric fi eld in the sample is less than a critical value Eth, called the threshold field, the sample obeys Ohm's law. When E exceeds Eth but is less than a sustaining value Es, the slope of J-E curve is negative, i.e. the differential resistance of the device is negative.
- This differential negative resistance (usually stated as the "negative resistance") of the device is utilized for making microwave Gunn oscillators.
- When the negative resistance of the device is compensated by the positive resistance of the external resonance circuit, sustained oscillations take place.
- The value of the threshold field varies with the type of the semiconductor materials used. (2 marks)

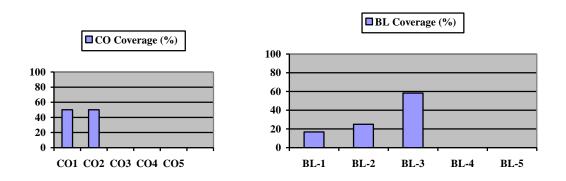
Microwave Generation

- The high field domain moves through the sample with uniform velocity and gets collected at the anode. A new domain is again formed at the cathode and the process repeats itself.
- Thus, a pulse current output is obtained with the intrinsic period T equal to the transit time of the domain through the effective length l_{eff} of the sample:

			1		
	r_{-} $l_{ m eff}$				
	$T = \frac{l_{\text{eff}}}{v_d}$				
	The intrinsic frequency of oscillation is given by				
	$1 v_d$				
	$f = \frac{1}{T} = \frac{v_d}{l_{eff}}$				
	W .				
	• where v _d is the domain velocity (approximately the drift				
	velocity of electrons) and the effective length that the				
	domain travels $l_{eff} = l$, the sample length.				
	• Since the drift velocity is very high and the semiconductor				
	length is very small, the current fluctuation occurs at				
	microwave frequencies to produce an output signal in the				
	low impedance external RF circuit. (2 marks)				
	ii) If the radar operates with a bias voltage of 10V and a				
	current of 200 mA, calculate the power dissipated. (2 Marks)				
	given:				
	Voltage (V) = 10 V				
	Current (I) = $200 \text{ mA} = 0.2 \text{ A}$ P = Vx I (1 mark)				
	P = 10 x 0.2 = 2 Watts (1 mark) A four-port device is designed to extract a portion of an input				
	signal while maintaining most of the power in the main path.				
	Explain its working principle and the factors affecting its				
	coupling efficiency. (7 Marks)				
	(* Marins)				
	Directional Coupler				
	A directional coupler is a four-port passive device				
4 (b)	commonly used for coupling a known fraction of the				
	microwave power to a port (coupled port) in the auxiliary				
	line while flowing from the input port to the output port in				
	the main line.				
	The remaining port is an ideally isolated port and matched				
	terminated.				
	• The performance of a directional coupler is measured in	_	_	_	
	terms of four basic parameters, i.e., coupling (C),	7	3	2	1
	transmission loss (T), directivity (D), and the return loss				
	(R) when all the ports are matched.				
	C (dB) = 10 log (Input power/Coupled output power)				
	$= 10 \log(P_1/P_4)$				
	(2 marks)				
	4 3				
	ct//				
	P4 \ P3				
	2///				
	P ₁ 2				
	(1 mark)				



Course Outcome (CO) and Bloom's level (BL) Coverage in Questions



Signature of Course Teacher